Sample Paper

Electronics & Communication Engineering

Max. Marks 100

Instructions for Candidates:

(A) A rectangular pulse

Attempt all 50 questions, each question carries 02 marks. There is no negative marking. Please mark the correct answer as A/B/C/D at appropriate place, on the right hand side of the question, in blue or black ink.

Q. 1	The very high frequency (VHF) range extends from			
	(A) 3-30MHz	(B) 30-300MHz		
	(C) 300-3000MHz	(D) 3000-30000MHz	[]
Q.2	The function of the transducer in a com (A) To transmit the massage signal	nmunication system is		
	(B) To modulate the massage signal			
	(C) To convert massage sound signal in	nto electrical signal		
	(D) None		[]
Q.3	time, then	m of a signal g (t) which is real and old sy	mmetr	ic in
	(A) G (f) is complex	(B) G (f) is imaginary		
	(C) G (f) is real	(D) G (f) is real and non negative	[]
Q.4	The trigonometric Fourier series of an (A) dc term	even function of time does not have the (B) cosine terms		
	(C) sin terms	(D) odd harmonic terms	[]
Q.5		deterministic signal is given by $[sine(f)/]$	f2], w	here
	1 is frequency. The auto correlation fun	ction of this signal in the time domain is		

(C) Sine pulse	(D) Triangular pulse	[]

(B) A delta function

Q.6 A 4GHz carrier is DSB-SC modulated by a low pass message signal with maximum

	frequency of 2MHz. The resultant sign of the sampling in train should be	al is to be ideally sampled. The minimum	freque	ency
	(A) 4MHz	(B) 8MHz		
	(C) 8GHz	(D) 8.004GHz	[]
Q.7	The maximum power efficiency of AM	modulator is		
	(A) 25%	(B) 50%		
	(C) 75%	(D) 100%	[]
Q.8	Q.8 1 MHz sinusoidal carrier is amplitude modulated by symmetrical square wa 100per sec. which of the following frequency will not be present in the modulate (A) 990KHz (B) 1010KHz			
	(C) 1020KHz	(D) 1030KHz	[]
Q.9	The probability density function of the	envelope of narrowband Gaussian noise is		
	(A) Poisson	(B) Gaussian		
	(C) Rayleigh	(D) Rician	[]
Q.10	The amplitude spectrum of a Gaussian J	pulse is		
	(A) Uniform	(B) A sine function		
	(C) Gaussian	(D) An impulse function	[]
Q.11	The space charge limited current in a in	a thermionic diode is given by		
	(A) Richardson's equation	(B) Child-Langmuir equation		
	(C) Plank constant	(D) none	[]
Q.12	Schottky effect originates from			
	(A) Field emission	(B) Photo electric emission		
Q.13	(C) Secondary emissionA good ohmic contacts is obtained with	(D) none	[]
	(A) A wide band gap semiconductor	(B) A low barrier height		
	(C) Low doping	(D) None	[]
0.14	The reverse saturation current desity of	a schottky diode is		

Q.14 The reverse saturation current desity of a schottky diode is

(A) Much larger than that of a pn junction diode(B) Much less than that of a pn junction diode

	(C) Equal to that of a pn junction diode(D) None	2	[]
Q.15	The cutin voltage of a si p-n diode is about			
	(A) 0.6v	(B) 0.6mv		
	(C) 6v	(D) None	[]
Q.16	The emission from a laser is spontaneous /stimulated			
	(A) a tunnel diode offers	(B) a negative resistance		
	(C) a negative differential resistance	(D) None	[]
Q.17	If α =0.95, then the value of β of the tra	unsistor is		
	(A) 190	(B) 19		
	(C) 0.05	(D) None	[]
Q.18	A transistor is an amplifier circuit is			
	(A) An active element	(B) A passive element		
	(C) Both	(D) None	[]
Q.19	9 The self-bias arrangement gives a better Q-point stability when			
	(A) Re is small	(B) β is small, but Re is large		
	(C) Both β and Re are large	(D) None	[]
Q.20	For a emitter follower the gain is			
	(A) Unity	(B) Greater than unity		
	(C) Less than unity	(D) None	[]
Q.21	A Hartley oscillator is used in the - (A) dc supply	(B) AC supply		
	(C) Both	(D) None	[]
Q.22	Q.22 The frequency stability of a crystal oscillator is			
	(A) Very high	(B) Very Low		

	(C) Both	(D) None	[]
Q.23	If E= $(3x^2+y)$ ax+ xay kv/m, what is t to (2,-1,0) by taking the path (0,5,0) \rightarrow (A) 12mJ	he work done in moving a-2 μ c charge from (2,5,0) \rightarrow (2,-1,0) (B) 6mJ	m (0,5	,0)
	(C) 10mJ	(D) None	[]
Q.24	A telephone line has R=30/km, L= 100r	nH/km, G=0 and C = 20µF/km at f=1 kHz	, what i	is

characteristic impedance of the line. (A) 70.75L-1.367° Ω (B) 60.82L-1.827°Ω (D) None of these (C) $80.87L-1.367^{\circ}\Omega$ 1 ſ

Q.25 A certain antenna with an efficiency of 95% has Maximum radiation intensity of 0.5% w/sr., Input power is 0.4W, what is directivity is (A) 20.94 (B) 15.67 (D) 8.12 (C) 25.11

Q.26 z- transform of u (-n) is

(A)
$$\frac{z}{1-z}$$
 (B) $\frac{z}{1-z}$
(C) $\frac{1}{1-z}$ (D) $\frac{z^2}{1-z}$ []

[

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- Q.27 If $x(n) \leftrightarrow X(Z)$, then valid one is (A) $x(-n) \leftrightarrow X(Z)$ (B) $x(-n) \leftrightarrow zX(Z)$ (C) $x(-n) \leftrightarrow \frac{X(Z)}{7}$ (D) $x(-n) \leftrightarrow X(\frac{1}{7})$] ſ
- Q.28 z- transform of $[a \times (n)+b \times (n)]$ is (A) a x(z)+b x(z)(B) a x(z)b x(z)(C) a x(z)-b x(z)(D) None of these] ſ
- Q.29 The Boolean expression Y = A.B represent (A) OR gate (B) XNOR gate (C) AND gate (D) None 1 ſ
- Q.30 Number of bits in nibble is (A) Two (B) Three

	(C) Four	(D) Eight	[]
Q.31	A flip- flop is			
	(A) By stable multivibrator circuit	(B) Mono stable multivibrator circuit		
	(C) 1 & 2 both	(D) None	[]
Q.32	The voltage gain of FET source follows (A) -1	er is (B) greater than 1		
	(C) Slightly less than unity and positive	(D) None	[]
Q.33	A maximum saturation drain current can be attained in an n- channel JFET when Vgs is equal to			
	(A) pinch-off voltage	(B) zero		
	(C) -4v	(D) None	[]
Q.34	An OP-AMP comparator circuit employ	ys		
	(A) No feedback	(B) Positive		
	(C) Negative feedback	(D) None	[]
Q.35	The high input impedance of an IC OP-	AMP is achieved by using		
	(A) FET	(B) CE transistor		
	(C) Darlington connection	(D) None	[]
Q.36	The input impedance of an active filter	is		
	(A) Zero	(B) 100Ω		
	(C) range from few $K\Omega$ to thousand $M\Omega$	(D) None	[]
Q.37	For a second-order Butterworth LP filte	er, the damping factor is		
	(A) 2	(B) 1.414		
	(C) 0.707	(D) None	ſ	1
Q.38	A toggle switch operation is obtained fr	rom	L	1
	(A) RS-Flip-flop	(B) T-type FF		
	(C) JK- FF	(D) None	[]
Q.39	A CPU built on a single semiconductor	chip serves as a		
	(A) Microprocessor	(B) Microcontroller		

	(C) Computer	(D) None	[]
Q.40	In VLSI technology, the rectangles photographic plate called	composing the image of mask expo	sed	on a
	(A) Reticle (C) Both	(B) Silicide(D) None	[]
Q.41	The main component of CRO is			
	(A) CRT	(B) Gun diode		
	(C) H-V plate	(D) None	[]
Q.42	A radar antenna generally uses a ref	lector		
	(A) Parabolic	(B) Cylindrical		
	(C) Sphere	(D) None	[]
Q.43	A color camera employsvidicon tu	ubes		
	(A) Three	(B) Four		
	(C) Five	(D) None	[]
Q.44	The carrier frequency of the audio signal in TV transmission is greater than that for video signal by			video
	(A) 4.5MHz	(B) 5.5MHz		
	(C) 10.5MHz	(D) None	[]
Q.45	⁴⁵ Microwave components can be characterized by			
-	(A) h-parameter	•		
	(C) S-parameter	(D) Z-parameter	[]
Q.46	The state-space representation for multi-	variable system can write as?		
	(A) X=Ax+BU	(B) X=AX+BU		
	(C) X= AX+BU	(D) None	[]
Q.47	The signal x (t) = $\cos(2\prod)(100t) + 5\sin(2\pi)$	2∏)(40t) is	-	_
	(A) Periodic	(B) None Periodic		
	(C) Both, (A) & (B)	(D) None	[]
Q.48	How many buses of 8085 microprocesso	Dr		
	(A) Two	(B) Three		

	(C) Four	(D) None	[]
Q.49	9 ICBO for every 100C rise in temperature			
	(A) Doubles	(B) Triples		
	(C) Quadruples	(D) None	[]
Q.50	If $x(n) \leftrightarrow X(Z)$, then valid one is			
	(A) $x(-n) \leftrightarrow X(Z)$	(B) $x(-n) \leftrightarrow zX(Z)$		

(C)
$$x(-n) \leftrightarrow \frac{X(Z)}{z}$$
 (D) $x(-n) \leftrightarrow X(\frac{1}{z})$ []